



Description

The XPX4435XS uses advanced trench technology to provide excellent $R_{\rm DS(ON)}$, low gate charge and operation with gate voltages as low as 4.5V. This device is suitable for use as a load switch or in PWM applications.

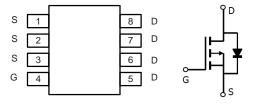
 V_{DS} =-30V, I_{D} =-10.5A $R_{DS}(ON)$ =12mΩ (typ) @ V_{GS} =10V $R_{DS}(ON)$ =18mΩ (typ) @ V_{GS} =4.5V

General Features

- High Power and current handing capability
- Lead free product is acquired
- Surface mount package

Application

- PWM applications
- Load switch
- Power management





Package Marking and Ordering Information

Product ID	Pack	Marking	Qty(PCS)
XPX4435XS	SOP-8	XPX4435XS XXX YYYY	3000

Absolute Maximum Ratings (TC=25℃unless otherwise noted)

Symbol	Parameter	Rating	Units
VDS	Drain-Source Voltage	-30	V
VGS	Gate-Source Voltage	±20	V
$I_D@T_A=25^{\circ}C$	Continuous Drain Current, V _{GS} @ -10V ¹	-10.5	А
I _D @T _A =70°C	Continuous Drain Current, V _{GS} @ -10V ¹	-8.6	Α
IDM	Pulsed Drain Current ²	-50	А
EAS	Single Pulse Avalanche Energy ³	72.2	mJ
IAS	Avalanche Current	-38	Α
P _D @T _A =25°C	Total Power Dissipation ⁴	3.1	W
P _D @T _A =70℃	Total Power Dissipation ⁴	2	W
TSTG	Storage Temperature Range	-55 to 150	$^{\circ}\!\mathbb{C}$
TJ	Operating Junction Temperature Range	-55 to 150	°C
R₀JA	Thermal Resistance Junction-Ambient ¹	75	°C/W
R₀JA	Thermal Resistance Junction-Ambient ¹(t≦ 10s)	40	°C/W
R₀JC	Thermal Resistance Junction-Case ¹	24	°C/W



Electrical Characteristics (T_J=25°C, unless otherwise noted)

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit	
BVDSS	Drain-Source Breakdown Voltage	V _{GS} =0V , I _D =-250uA	-30	-32		V	
△BVDSS/△TJ	BV _{DSS} Temperature Coefficient	Reference to 25℃, I _D =-1mA		-0.022		V/℃	
RDS(ON)	Static Drain-Source On-Resistance ²	V _{GS} =-10V , I _D =-10A		12	16	mΩ	
` ,		V _{GS} =-4.5V , I _D =-5A		18	24	11122	
VGS(th)	Gate Threshold Voltage	V _{GS} =V _{DS} , I _D =-250uA	-1.0	-1.6	-2.5	V	
$\triangle V_{GS(th)}$	$V_{\text{GS(th)}}$ Temperature Coefficient	,		4.6		mV/℃	
IDSS	Drain-Source Leakage Current	V _{DS} =-24V , V _{GS} =0V , T _J =25°C			-1	uA	
		V _{DS} =-24V , V _{GS} =0V , T _J =55°C			-5		
IGSS	Gate-Source Leakage Current	V_{GS} =±20 V , V_{DS} =0 V			±100	nA	
gfs	Forward Transconductance	V_{DS} =-5 V , I_{D} =-5 A		17		S	
R_g	Gate Resistance	V _{DS} =0V , V _{GS} =0V , f=1MHz		13		Ω	
Qg	Total Gate Charge (-4.5V)			30			
Qgs	Gate-Source Charge	V _{DS} =-15V , V _{GS} =-4.5V , I _D =- 6A		6		nC	
Qgd	Gate-Drain Charge	57.		9			
Td(on)	Turn-On Delay Time			10			
Tr	Rise Time	V_{DD} =-15V , V_{GS} =-10V , R_{G} =3.3 Ω ,		26		no	
Td(off)	Turn-Off Delay Time	I _D =-6A		35		ns	
Tf	Fall Time			8			
Ciss	Input Capacitance			1800			
Coss	Output Capacitance	V _{DS} =-15V , V _{GS} =0V , f=1MHz		305		pF	
Crss	Reverse Transfer Capacitance			216			
IS	Continuous Source Current ^{1,5}	\/ -\/ -0\/ Fares Current			-10	Α	
ISM	Pulsed Source Current ^{2,5}	V _G =V _D =0V , Force Current			-50	Α	
VSD	Diode Forward Voltage ²	V _{GS} =0V , I _S =-1A , T _J =25℃			-1.2	V	
trr	Reverse Recovery Time	IF=-6A , dI/dt=100A/μs ,		16.3		nS	
Qrr	Reverse Recovery Charge	TJ=25℃		5.9		nC	

Note:

- 1. The data tested by surface mounted on a 1 inch 2 FR-4 board with 2OZ copper.
- 2. The data tested by pulsed , pulse width $\, \leqq \,$ 300us , duty cycle $\, \leqq \,$ 2%
- 3. The EAS data shows Max. rating . The test condition is VDD=-25V,VGS=-10V,L=0.1mH,IAS=-38A
- 4. The power dissipation is limited by 150 $^\circ\!\mathrm{C}$ junction temperature
- 5. The data is theoretically the same as ID and IDM, in real applications, should be limited by total power dissipation.



Typical Characteristics

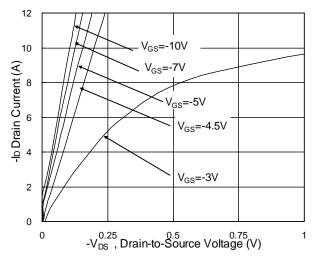


Fig.1 Typical Output Characteristics

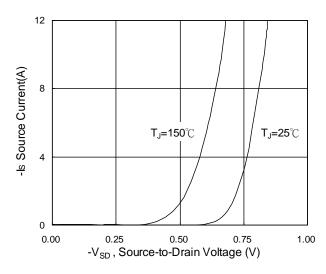


Fig.3 Forward Characteristics of Reverse

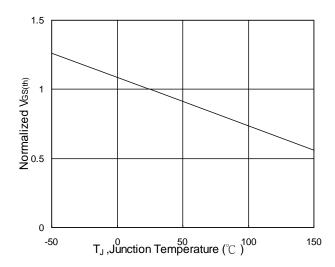


Fig.5 Normalized V_{GS(th)} vs. T_J

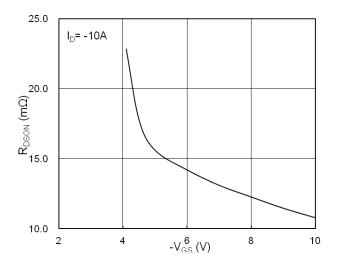


Fig.2 On-Resistance vs. G-S Voltage

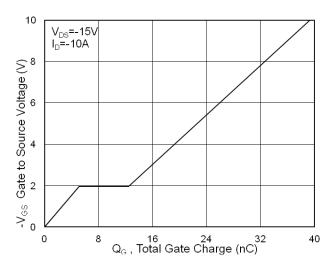


Fig.4 Gate-charge Characteristics

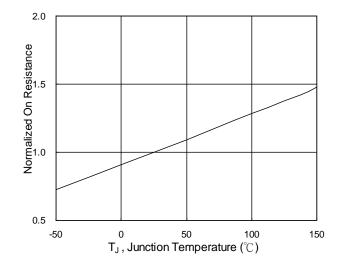
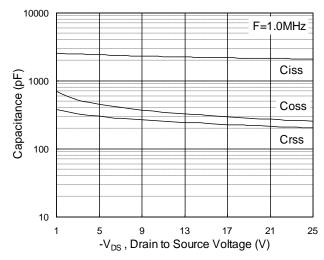


Fig.6 Normalized R_{DSON} vs. T_J





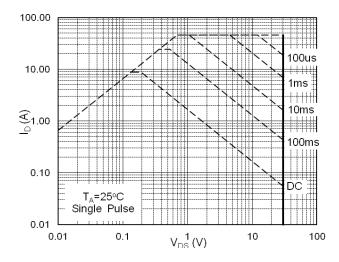


Fig.7 Capacitance

Fig.8 Safe Operating Area

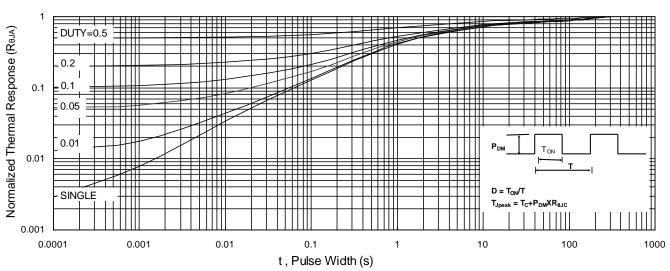


Fig.9 Normalized Maximum Transient Thermal Impedance

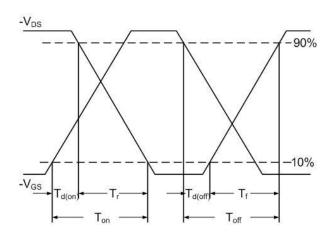


Fig.10 Switching Time Waveform

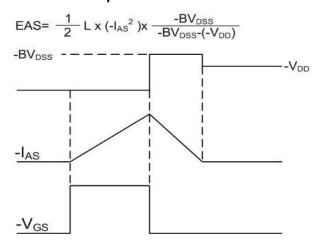
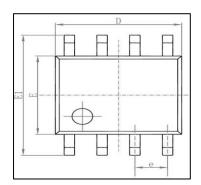
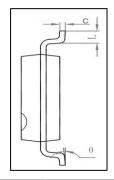


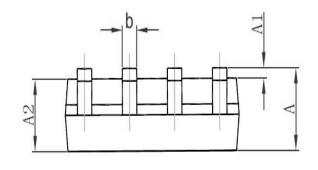
Fig.11 Unclamped Inductive Waveform



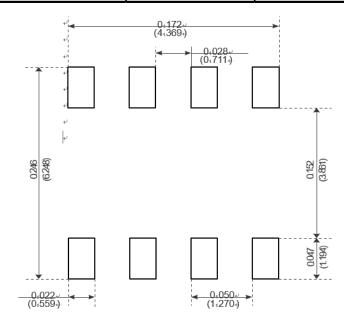
Package Mechanical Data-SOP-8







C	Dimensions Ir	n Millimeters	Dimensions	In Inches
Symbol	Min	Max	Min	Max
Α	1. 350	1. 750	0. 053	0.069
A1	0. 100	0. 250	0. 004	0. 010
A2	1. 350	1. 550	0. 053	0. 061
b	0. 330	0. 510	0. 013	0. 020
С	0. 170	0. 250	0.006	0. 010
D	4. 700	5. 100	0. 185	0. 200
E	3.800	4. 000	0. 150	0. 157
E1	5. 800	6. 200	0. 228	0. 244
е	1. 270	(BSC)	0. 050	(BSC)
L	0. 400	1. 270	0. 016	0.050
θ	0°	8°	0°	8°



Recommended Minimum Pads



Flow (wave) soldering (solder dipping)

Product	Peak Temperature	Dipping Time
Pb device	245℃±5℃	5sec±1sec
Pb-Free device	260℃+0/-5℃	5sec±1sec



This integrated circuit can be damaged by ESD UniverChip Corporation recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedure can cause damage. ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

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